

Observation of an emerging equilibrium indirect exciton condensate in double bilayer graphene-WSe₂ heterostructures

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Electronic double layers, consisting of two two-dimensional (2D) semiconductors separated by a dielectric, are an ideal platform for probing indirect exciton physics. When the two 2D layers are doped with equal and opposite charge densities, at a sufficiently small interlayer separation electrons and holes in opposite layers can couple and form equilibrium indirect excitons. We present here a study of rotationally aligned double bilayer graphene heterostructures, separated by bilayer WSe₂.

Rotational alignment of the graphene bilayers ensures that tunneling between layers conserves both energy and momentum, resulting in tunneling characteristics that agree well with single particle tunneling calculations. By using a dual gated structure with multiple contacts to each layer, we can electrostatically dope each graphene layer individually, and probe the intrinsic tunneling current-voltage characteristics. When the two graphene bilayers are doped with equal and opposite charge densities, the tunneling amplitude is dramatically enhanced relative to single particle expectations, showing a vertical onset at zero interlayer bias. The tunneling enhancement is strongly dependent on temperature, with the enhancement largely suppressed above $T = 5$ K. Furthermore, the enhancement is fully suppressed by applying an in-plane magnetic field. These experimental observations suggest the emergence of a nascent indirect exciton condensate in double bilayer graphene heterostructures (Fig. 1).

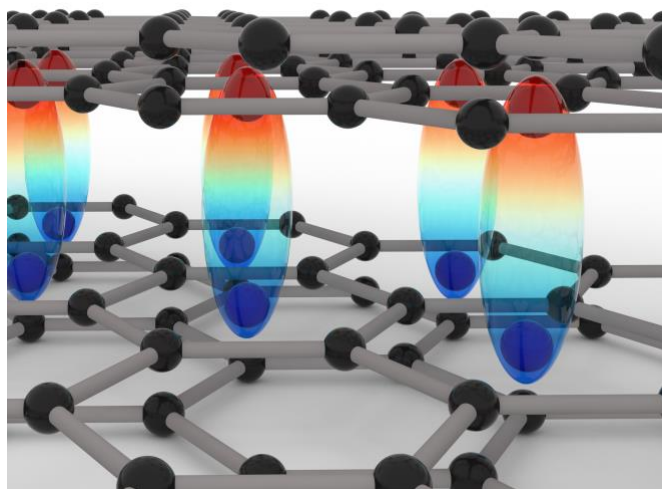


Fig. 1. Schematic illustration of indirect exciton formation in a double bilayer graphene heterostructure.